

# 2N3838

## 2N3838 Information

Heisener.com	Part Number	2N3838
	Manufacturer	Microsemi Corporation
	Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Arrays
	Description	TRANS NPN/PNP 40V 0.6A 6 PFLTPK
	Package	6-FlatPack
		For the pricing/inventory/lead time, please contact
or Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com



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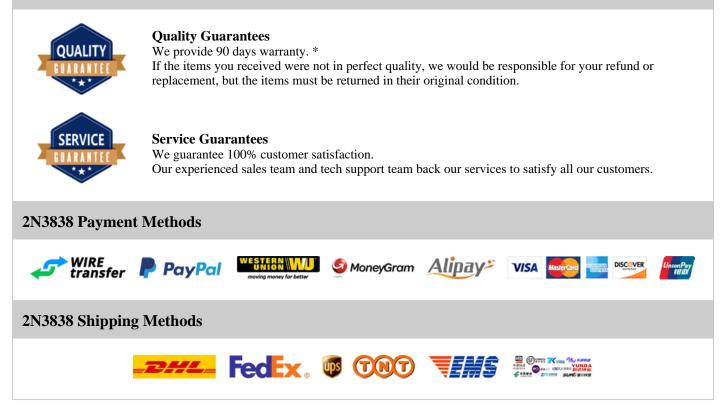
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#### 2N3838 Specifications

Manufacturer Part Number2N3838ManufacturerMicrosemi CorporationCategoryDiscrete Semiconductor ProductsTransistors - Bipolar (BJT) - ArraysPackage6-FlatPackSeries-Transistor TypeNPN, PNPCurrent - Collector (Ic) (Max)600mAVoltage - Collector Emitter Breakdown (Max)40VVce Saturation (Max) @ Ib, Ic10µA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce100 @ 150mA, 10VPower - Max350mWFrequency - Transition-Operating Temperature-65°C ~ 200°C (TJ)Mounting TypeSurier Manu		
CategoryDiscrete Semiconductor ProductsTransistors - Bipolar (BJT) - ArraysPackage6-FlatPackSeries-Transistor TypeNPN, PNPCurrent - Collector (Lo (Max)600mAVoltage - Collector Emitter Breakdown (Max)400wV @ 15mA, 150mAVce Saturation (Max) @ Ib, Ic10µA (ICBO)Current - Collector Cutoff (Max)100 @ 150mA, 10VPower - Max350mWFrequency - Transition-Operating Temperature-65°C ~ 200°C (TJ)Mounting TypeSurface Mount	Manufacturer Part Number	2N3838
Transistors - Bipolar (BJT) - ArraysPackage6-FlatPackSeries-Transistor TypeNPN, PNPCurrent - Collector (Lo) (Max)600mAVoltage - Collector Emitter Breakdown (Max)40VVce Saturation (Max) @ Ib, Ic400mV @ 15mA, 150mACurrent - Collector Cutoff (Max)10µA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce100 @ 150mA, 10VPower - Max350mWFrequency - Transition-Operating Temperature65°C ~ 200°C (TJ)Mounting TypeSurface Mount	Manufacturer	Microsemi Corporation
Package6-FlatPackSeries-Transistor TypeNPN, PNPCurrent - Collector (Lo) (Max)600mAVoltage - Collector Emitter Breakdown (Max)40VVotage - Collector Emitter Breakdown (Max)400mV @ 15mA, 150mACurrent - Collector Cutoff (Max)10µA (ICBO)DC Current Gain (hFE) (Min) @ Lc, Vce100 @ 150mA, 10VPower - Max550mWFrequency - Transition-Operating Temperature-65°C ~ 200°C (TJ)Mounting TypeSurface Mount	Category	Discrete Semiconductor Products
Series-Transistor TypeNPN, PNPCurrent - Collector (Ic) (Max)600mAVoltage - Collector Emitter Breakdown (Max)40VVce Saturation (Max) @ Ib, Ic400mV @ 15mA, 150mACurrent - Collector Cutoff (Max)10µA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce100 @ 150mA, 10VPower - Max350mWFrequency - Transition-Operating Temperature-65°C ~ 200°C (TJ)Mounting TypeSurface Mount		Transistors - Bipolar (BJT) - Arrays
Transistor TypeNPN, PNPCurrent - Collector (Ic) (Max)600mAVoltage - Collector Emitter Breakdown (Max)40VVcc Saturation (Max) @ Ib, Ic400mV @ 15mA, 150mACurrent - Collector Cutoff (Max)10µA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce100 @ 150mA, 10VPower - Max350mWFrequency - Transition-Operating Temperature-65°C ~ 200°C (TJ)Mounting TypeSurface Mount	Package	6-FlatPack
Current - Collector (Ic) (Max)600mAVoltage - Collector Emitter Breakdown (Max)40VVcc Saturation (Max) @ Ib, Ic400mV @ 15mA, 150mACurrent - Collector Cutoff (Max)10µA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce100 @ 150mA, 10VPower - Max350mWFrequency - Transition-Operating Temperature-65°C ~ 200°C (TJ)Mounting TypeSurface Mount	Series	-
Voltage - Collector Emitter Breakdown (Max)40VVce Saturation (Max) @ Ib, Ic400mV @ 15mA, 150mACurrent - Collector Cutoff (Max)10µA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce100 @ 150mA, 10VPower - Max350mWFrequency - Transition-Operating Temperature-65°C ~ 200°C (TJ)Mounting TypeSurface Mount	Transistor Type	NPN, PNP
Vce Saturation (Max) @ Ib, Ic 400mV @ 15mA, 150mA   Current - Collector Cutoff (Max) 10µA (ICBO)   DC Current Gain (hFE) (Min) @ Ic, Vce 100 @ 150mA, 10V   Power - Max 350mW   Frequency - Transition -   Operating Temperature -65°C ~ 200°C (TJ)   Mounting Type Surface Mount	Current - Collector (Ic) (Max)	600mA
Current - Collector Cutoff (Max)10μA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce100 @ 150mA, 10VPower - Max350mWFrequency - Transition-Operating Temperature-65°C ~ 200°C (TJ)Mounting TypeSurface Mount	Voltage - Collector Emitter Breakdown (Max)	40V
DC Current Gain (hFE) (Min) @ Ic, Vce 100 @ 150mA, 10V   Power - Max 350mW   Frequency - Transition -   Operating Temperature -65°C ~ 200°C (TJ)   Mounting Type Surface Mount	Vce Saturation (Max) @ Ib, Ic	400mV @ 15mA, 150mA
Power - Max350mWFrequency - Transition-Operating Temperature-65°C ~ 200°C (TJ)Mounting TypeSurface Mount	Current - Collector Cutoff (Max)	10μA (ICBO)
Frequency - Transition-Operating Temperature-65°C ~ 200°C (TJ)Mounting TypeSurface Mount	DC Current Gain (hFE) (Min) @ Ic, Vce	100 @ 150mA, 10V
Operating Temperature-65°C ~ 200°C (TJ)Mounting TypeSurface Mount	Power - Max	350mW
Mounting Type Surface Mount	Frequency - Transition	-
	Operating Temperature	-65°C ~ 200°C (TJ)
	Mounting Type	Surface Mount
Package / Case 6-FlatPack	Package / Case	6-FlatPack
Supplier Device Package 6-Flatpack	Supplier Device Package	6-Flatpack
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#### 2N3838 Guarantees



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